# NSN 5962-01-352-7927

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#### **Body Length:**

Between 0.540 inches and 0.560 inches

## Body Width:

Between 0.442 inches and 0.458 inches

## **Body Height:**

Between 0.060 inches and 0.120 inches

# Maximum Power Dissipation Rating:

300.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### Features Provided:

Ultraviolet erasable and w/enable and programmed and monolithic

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Leadless flat pack

#### **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

## Input Circuit Pattern:

17 input

## Case Outline Source And Designator:

C-12 mil-m-38510

## **Current Rating Per Characteristic:**

25.00 milliamperes reverse current, dc absolute

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.6 volts power source and 6.25 volts power source

## Capitance Rating Per Characteristic:

10.00 input picofarads and 14.00 output picofarads

#### **Time Rating Per Chacteristic:**

250.00 nanoseconds af output megawatts

#### Memory Device Type:

Eprom

## **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

32 leadless

#### Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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